

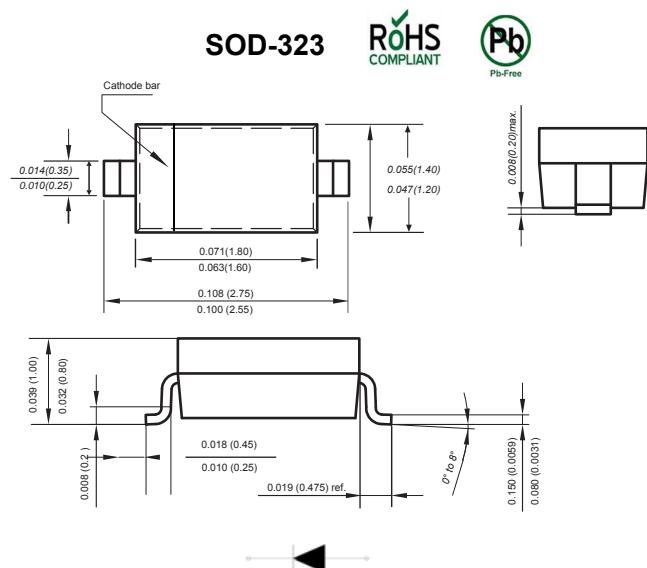
FEATURES

- Ultra high-speed switching
- Very low forward voltage
- Guard ring protected
- Very small SMD plastic package

APPLICATIONS

- Ultra high-speed switching
- Voltage clamping
- Protection circuits.

Marking: A4



Dimensions in inches and (millimeters)

MAXIMUM RATING @ Ta=25°C unless otherwise specified

Parameter	Symbol	Limits	Unit
continuous reverse voltage	V _R	20	V
continuous forward current	I _F	1	A
Forward Surge Current	I _{FSM}	5	A
Total Power Dissipation	P _{tot}	350	mW
Junction temperature	T _j	125	°C
Storage temperature range	T _{stg}	-65 to +150	°C

ELECTRICAL CHARACTERISTICS @ Ta=25°C unless otherwise specified

Parameter	Symbol	Conditions	Typ.	Max.	Unit
Forward voltage	V _F	I _F =10mA	240	270	mV
		I _F =100mA	300	350	
		I _F =1A	480	550	
Reverse current	I _R	V _R =5v	5	10	μA
		V _R =8v	7	20	
		V _R =15v	10	50	
Capacitance between terminals	C _d	V _R =5v,f=1MHz	19	25	pF

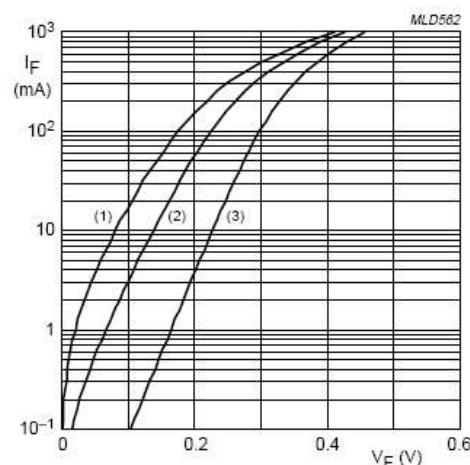
TYPICAL CHARACTERISTICS @ Ta=25°C unless otherwise specified


Fig.2 Forward current as a function of forward voltage; typical values.

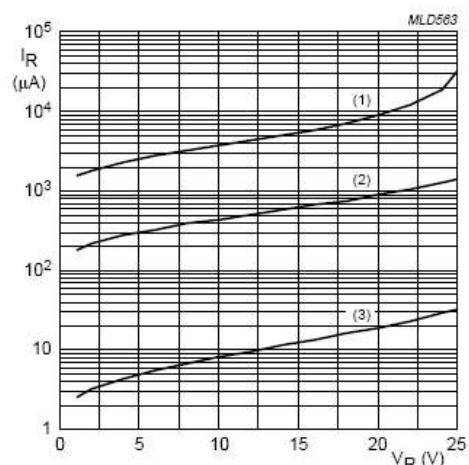


Fig.3 Reverse current as a function of reverse voltage; typical values.

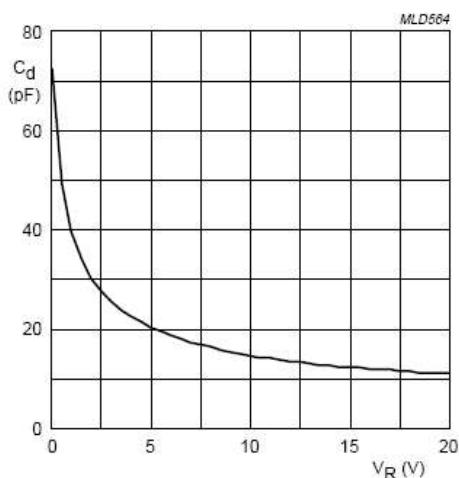


Fig.4 Diode capacitance as a function of reverse voltage; typical values.